

KSD1417

High Power Switching Applications

- High DC Current Gain
- Low Collector-Emitter Saturation Voltage
- Complement to KSB1022



NPN Silicon Darlington Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	60	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	7	Α
I _{CP}	Collector Current (Pulse)	10	Α
I _B	Base Current	0.7	А
P _C	Collector Dissipation (T _a =25°C)	2	W
P _C	Collector Dissipation (T _C =25°C)	30	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 50 \text{mA}, I_B = 0$	60			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 60V, I_{E} = 0$			100	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			3	mA
h _{FE1}	DC Current Gain	$V_{CE} = 3V, I_{C} = 3A$	2K		15K	
h_{FE2}		$V_{CE} = 3V, I_{C} = 7A$	1K			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 3A$, $I_B = 6mA$		0.9	1.5	V
		$I_C = 7A, I_B = 14mA$		1.2	2	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 3A$, $I_B = 6mA$		1.5	2.5	V
t _{ON}	Turn ON Time	$V_{CC} = 45V, I_{C} = 4.5A$		0.8		μs
t _{STG}	Storage Time	$I_{B1} = -I_{B2} = 6mA$		3		μs
t _F	Fall Time	$R_L = 10\Omega$		2.5		μs

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V_{CE} = 3V

Typical Characteristics

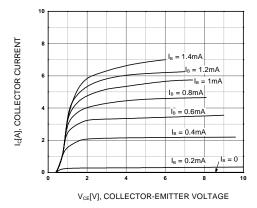


Figure 1. Static Characteristic

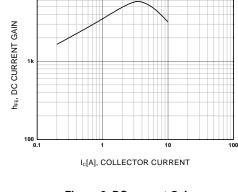


Figure 2. DC current Gain

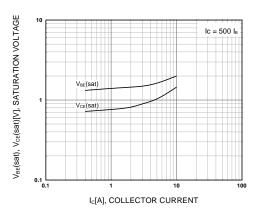


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

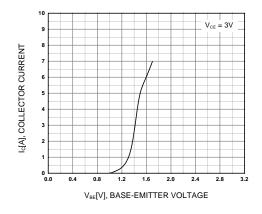


Figure 4. Base-Emitter On Voltage

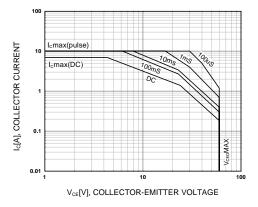


Figure 5. Safe Operating Area

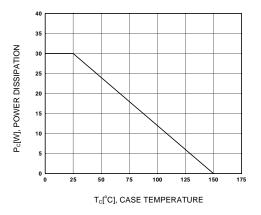
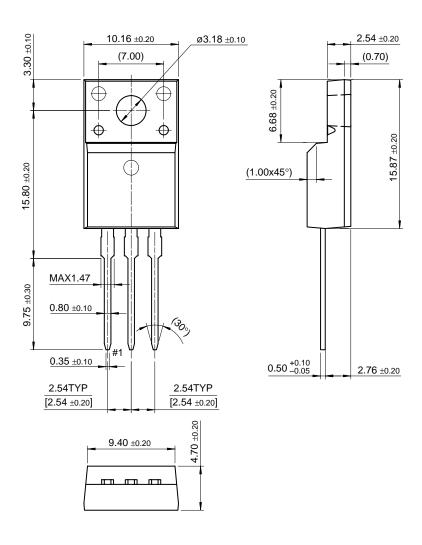


Figure 6. Power Derating

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Package Demensions

TO-220F



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